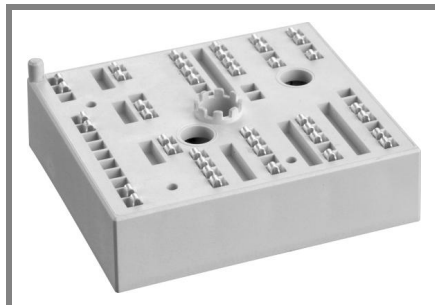


SKiiP 28ANB16V1



MiniSKiiP[®] 2

3-phase bridge rectifier + brake chopper

SKiiP 28ANB16V1

Features

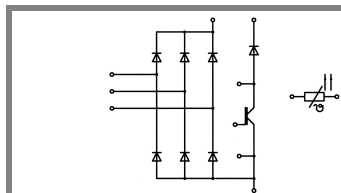
- Fast Trench IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

Typical Applications

- Input bridge for Inverter up to 39 kVA

Remarks

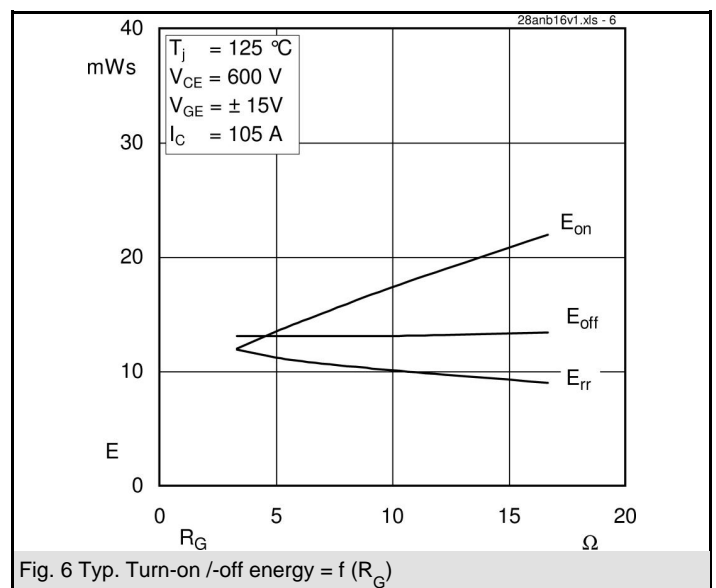
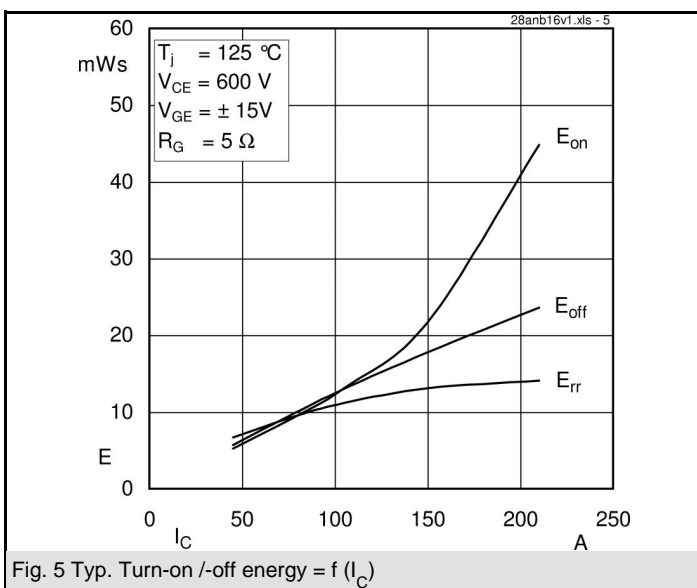
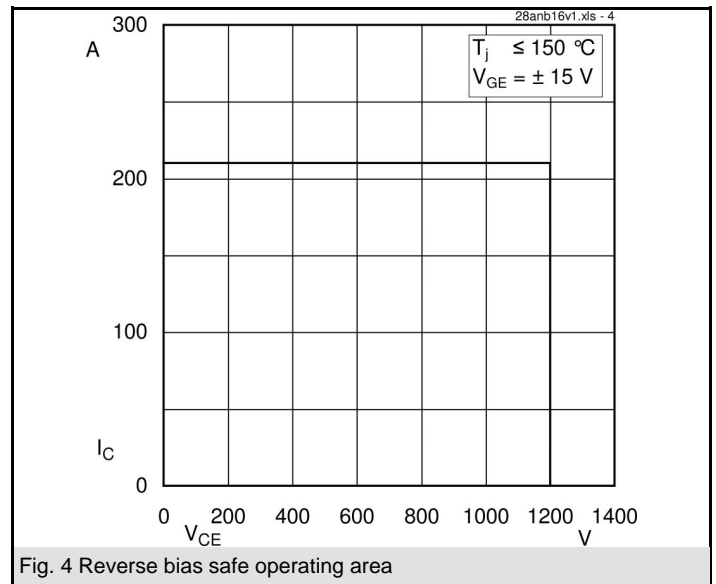
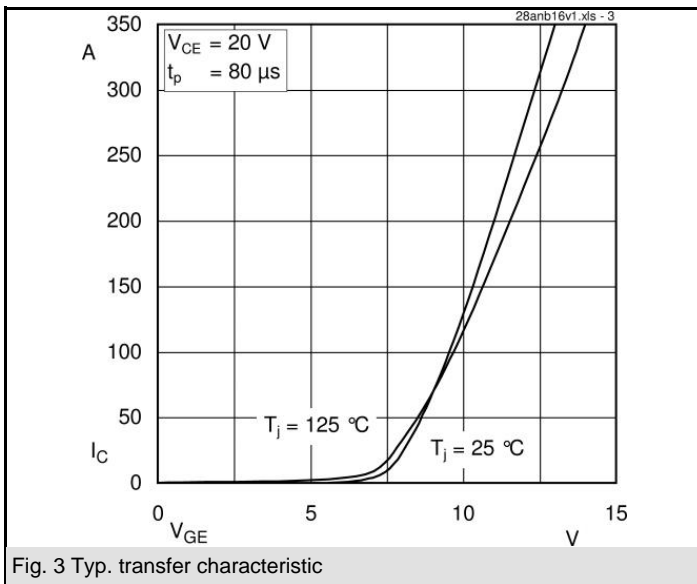
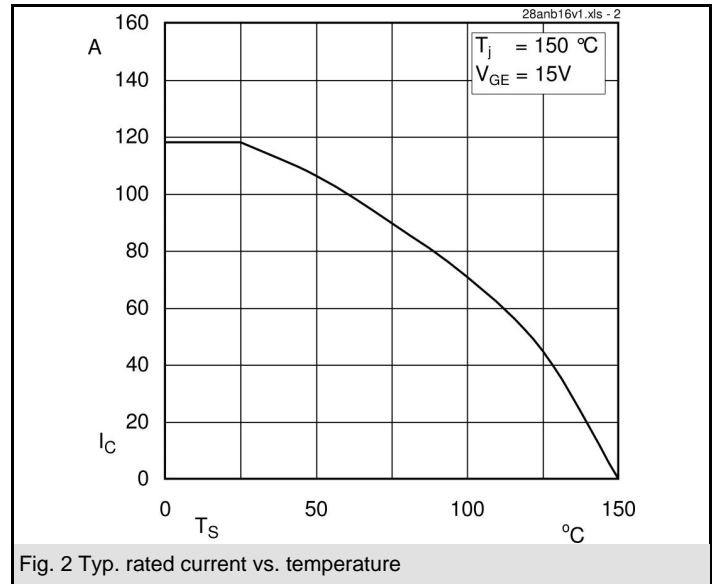
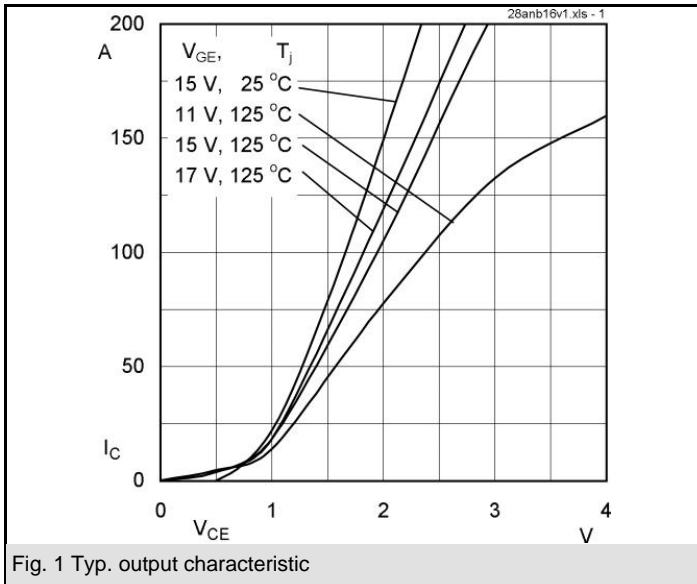
- V_{CEsat} , V_F = chip level value



ANB

Absolute Maximum Ratings		$T_s = 25\text{ °C}$, unless otherwise specified		
Symbol	Conditions	Values	Units	
IGBT - Chopper				
V_{CES}	$T_s = 25\text{ (70) °C}$ $t_p \leq 1\text{ ms}$	1200	V	
I_C		118 (88)	A	
I_{CRM}		210	A	
V_{GES}		± 20	V	
T_j		- 40 ... + 150	°C	
Diode - Chopper				
I_F	$T_s = 25\text{ (70) °C}$ $t_p \leq 1\text{ ms}$	118 (88)	A	
I_{FRM}		210	A	
T_j		- 40 ... + 150	°C	
Diode - Rectifier				
V_{RRM}	$T_s = 70\text{ °C}$	1600	V	
I_F		83	A	
I_{FSM}		$t_p = 10\text{ ms, sin } 180\text{ °, } T_j = 25\text{ °C}$	1000	A
i^2t		$t_p = 10\text{ ms, sin } 180\text{ °, } T_j = 25\text{ °C}$	6600	A ² s
T_j		- 40 ... + 150	°C	
I_{tRMS}	per power terminal (20 A / spring)	120	A	
T_{stg}	$T_{op} \leq T_{stg}$	- 40 ... + 125	°C	
V_{isol}	AC, 1 min.	2500	V	

Characteristics		$T_s = 25\text{ °C}$, unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
IGBT - Chopper					
V_{CEsat}	$I_{Cnom} = 105\text{ A, } T_j = 25\text{ (125) °C}$		1,7 (2)	2,1 (2,4)	V
$V_{GE(th)}$	$V_{GE} = V_{CE}, I_C = 3\text{ mA}$	5	5,8	6,5	V
$V_{CE(TO)}$	$T_j = 25\text{ (125) °C}$		1 (0,9)	1,2 (1,1)	V
r_T	$T_j = 25\text{ (125) °C}$		6,7 (10)	8,6 (12)	mΩ
C_{ies}	$V_{CE} = 25\text{ V, } V_{GE} = 0\text{ V, } f = 1\text{ MHz}$		8,4		nF
C_{oes}	$V_{CE} = 25\text{ V, } V_{GE} = 0\text{ V, } f = 1\text{ MHz}$		1,5		nF
C_{res}	$V_{CE} = 25\text{ V, } V_{GE} = 0\text{ V, } f = 1\text{ MHz}$		1,1		nF
$R_{th(j-s)}$	per IGBT		0,4		K/W
$t_{d(on)}$	under following conditions		75		ns
t_r	$V_{CC} = 600\text{ V, } V_{GE} = \pm 15\text{ V}$		35		ns
$t_{d(off)}$	$I_{Cnom} = 105\text{ A, } T_j = 125\text{ °C}$		465		ns
t_f	$R_{Gon} = R_{Goff} = 5\text{ Ω}$		90		ns
E_{on}	inductive load		13,1		mJ
E_{off}			13		mJ
Diode - Chopper					
$V_F = V_{EC}$	$I_{Fnom} = 105\text{ A, } T_j = 25\text{ (125) °C}$		1,6 (1,6)	1,8 (1,8)	V
$V_{(TO)}$	$T_j = 25\text{ (125) °C}$		1 (0,8)	1,1 (0,9)	V
r_T	$T_j = 25\text{ (125) °C}$		5,7 (7,6)	6,7 (8,6)	mΩ
$R_{th(j-s)}$	per diode		0,55		K/W
I_{RRM}	under following conditions		175		A
Q_{rr}	$I_{Fnom} = 105\text{ A, } V_R = 600\text{ V}$		26		μC
E_{rr}	$V_{GE} = 0\text{ V, } T_j = 125\text{ °C}$		11,2		mJ
	$di_F/dt = 4000\text{ A/μs}$				
Diode - Rectifier					
V_F	$I_{Fnom} = 75\text{ A, } T_j = 25\text{ °C}$		1,2		V
$V_{(TO)}$	$T_j = 150\text{ °C}$		0,8		V
r_T	$T_j = 150\text{ °C}$		7		mΩ
$R_{th(j-s)}$	per diode		0,7		K/W
Temperature Sensor					
R_{ts}	3 %, $T_r = 25\text{ (100) °C}$		1000(1670)		Ω
Mechanical Data					
w			65		g
M_s	Mounting torque	2		2,5	Nm



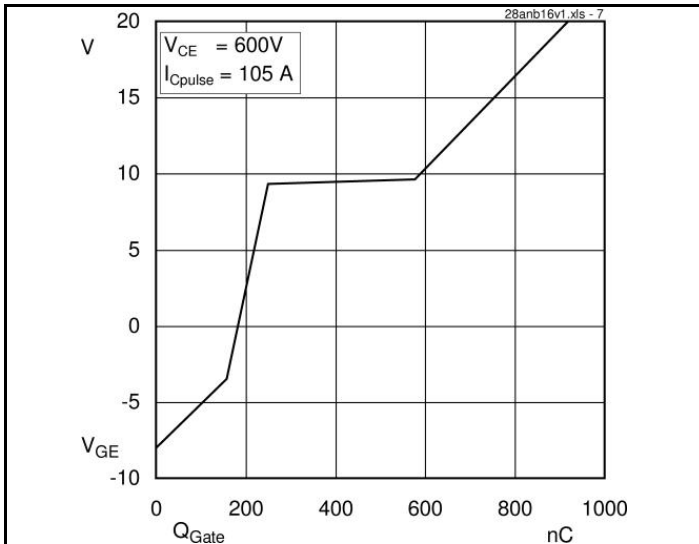


Fig. 7 Typ. gate charge characteristic

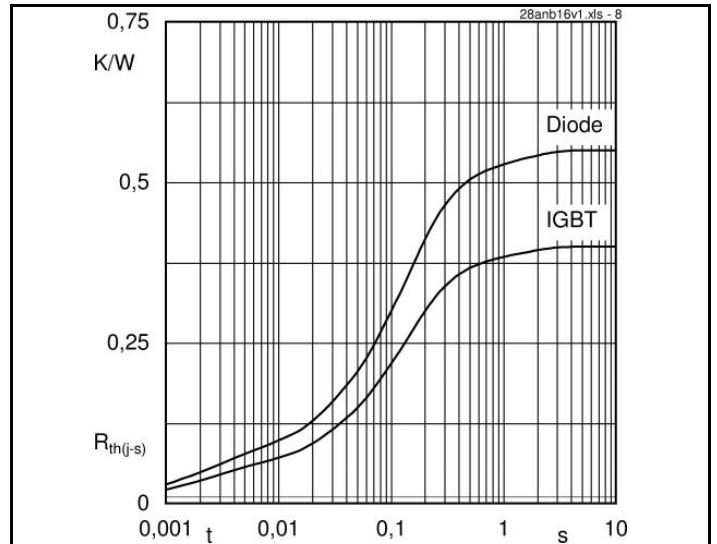


Fig. 8 Typ. thermal impedance

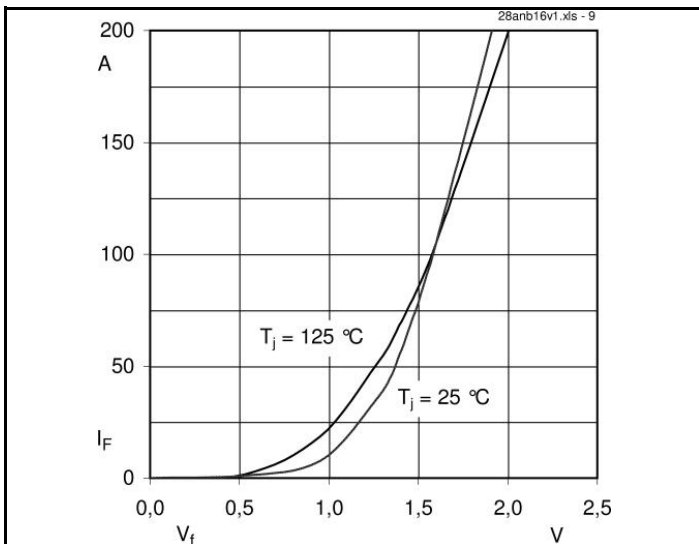


Fig. 9 Typ. freewheeling diode forward characteristic

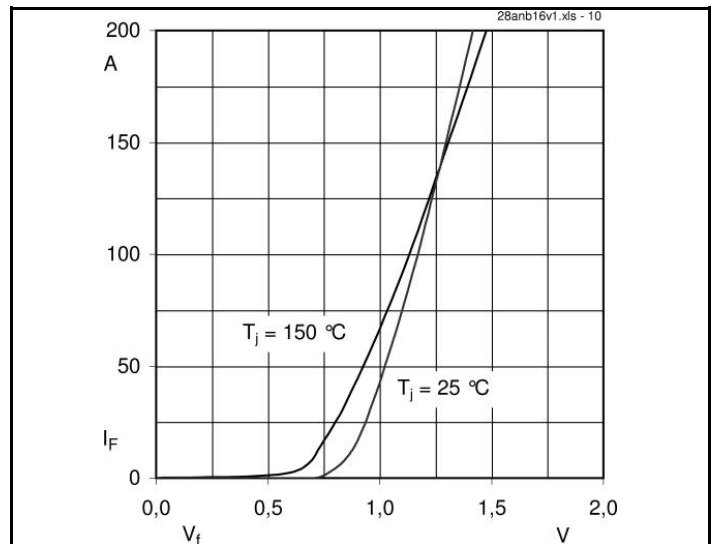


Fig. 10 Typ. input bridge forward characteristic

